

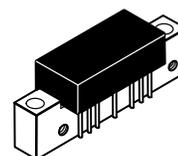
The RF Line High Output Power Doubler 750 MHz CATV Amplifiers

MHW7185A
MHW7205A

Designed specifically for 750 MHz CATV applications. Features ion-implanted, arsenic emitter transistors with an all gold metallization system.

- Supply Voltage = 24 Vdc
- 6th Generation Die Technology
- Specified for 110 Channel Performance
- Broadband Power Gain @ f = 50 MHz
Gp = 18 dB Min (MHW7185A)
Gp = 19.5 dB Min (MHW7205A)
- Broadband Noise Figure @ f = 50 MHz
NF = 6 dB Max
- Improvement in Distortion Over Conventional Hybrids
- Allows Higher Output Level Operation

750 MHz, 24 Vdc
110 CHANNEL
CATV AMPLIFIERS



CASE 714-06, Style 1

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
DC Supply Voltage	V _{CC}	+28	Vdc
RF Input Voltage (Single Tone)	V _{IN}	+70	dBmV
Operating Case Temperature Range	T _C	- 20 to +100	°C
Storage Temperature Range	T _{stg}	- 40 to +125	°C

ELECTRICAL CHARACTERISTICS (V_{CC} = 24 Vdc, T_C = 30°C, 75 Ω system, unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Bandwidth	BW	40	750	MHz
Power Gain (f = 50 MHz)	Gp1	18.0 19.5	19.0 20.5	dB
Power Gain (f = 750 MHz)	Gp2	18.5 20.0	20.5 21.5	dB
Slope (f = 40 – 750 MHz)	S	0	2	dB
Gain Flatness (f = 40 – 750 MHz, Peak to Valley)	G _f	—	1	dB
Return Loss (f = 40 MHz)	RL	18	—	dB
Return Loss Derate (f > 40 MHz)	RLD	—	0.007	dB/MHz
Composite Triple Beat (V _{out} = +44 dBmV/ch, 110 Channels, Worst Case)	CTB ₁₁₀	—	-58 -57	dBc
Cross Modulation (V _{out} = +44 dBmV/ch, 110 Channels, FM = 55 MHz)	XMD ₁₁₀	—	-65 -64	dBc
Composite Second Order (V _{out} = +44 dBmV/ch, 110 Channels, Worst Case)	CSO ₁₁₀	—	-58 -56	dBc
Noise Figure (f = 50 MHz)	NF ₁	—	6	dB
Noise Figure (f = 750 MHz)	NF ₂	—	8.5	dB
DC Current	IDC	380	460	mA

